# onsemi

## **Current-Shunt Monitors, 40 V Common Mode, Unidirectional, Single, Dual**

## NCS21673, NCV21673, NCS21674, NCV21674

The NCS21673 and NCS21674 are a series of current sense amplifiers offered in gains of 20, 50, 100 and 200 V/V. These parts can measure voltage across shunts at common mode voltages from -0.1 V to 40 V, independent of supply voltage. This helps measuring of fast transients and allows the same type of part to be used for high side and low side current sensing. These devices can operate from a single 2.7 V to 5.5 V power supply. With a -3 dB BW of up to 350 kHz and a Slew Rate of 2 V/us typical, the fast detection of current changes is ensured. These parts are available in TSOP–5 and Micro–8 packages. The dual version makes current sensing in multiple points of a system both space and cost effective.

#### Features

- Wide Common Mode Input Range: -0.1 V to 40 V
- Supply Voltage Range: 2.7 V to 5.5 V
- Low Offset Voltage
- Low Offset Drift
- Low Current Consumption: 300 µA max per channel
- NCV Prefix for Automotive Grade 1 and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q100 Qualified and PPAP Capable
- These Devices are Pb–Free, Halogen Free/BFR Free and are RoHS Compliant

#### Applications

- High–Side Current Sensing
- Low-Side Current Sensing
- Power Management
- Automotive

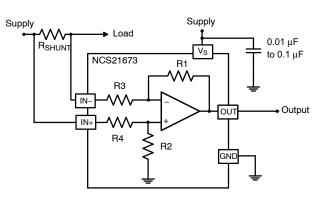
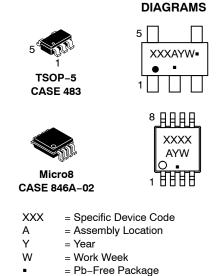


Figure 1. Example Application Schematic of High–Side Current Sensing

MARKING



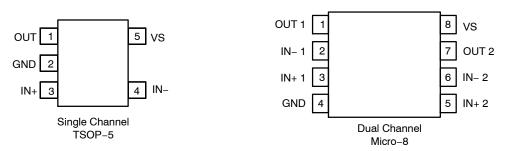
(Note: Microdot may be in either location)

**PIN CONNECTIONS** See pin connections on page 2 of this data sheet.

#### **ORDERING INFORMATION**

See detailed ordering and shipping information on page 14 of this data sheet.

#### **PIN FUNCTION DESCRIPTION**





#### **PIN DESCRIPTION**

Pin Name	Туре	Description
IN+ Input This pin is connected to the positive side of the sense resistor or current shun		This pin is connected to the positive side of the sense resistor or current shunt.
IN- Input This pin is connected to the negative side of the sense resistor or current shunt.		
OUT	Output	The output pin provides a low impedance voltage output.
V <sub>S</sub> Supply		This is the positive supply pin that provides power to the internal circuitry. An external bypass capacitor of 0.1 $\mu F$ is recommended to be placed as close as possible to this pin.
GND	Supply	This is the negative supply rail of the circuit.

#### **MAXIMUM RATINGS**

	Parameter	Symbol	Rating	Unit
Supply Voltage (Note	1)	Vs	-0.3 to 5.5	V
Angles leaves	Differential (V <sub>IN+</sub> )-(V <sub>IN-</sub> ) (Note 2)	$V_{IN+,} V_{IN-}$	±42	Analog
Analog Inputs	Common-Mode (Note 2)		-0.3 to +42	Inputs
Output		V <sub>OUT</sub>	GND-0.3 to (V <sub>s</sub> ) +0.3	V
Maximum Output Current		I <sub>OUT</sub>	TBD	mA
Input Current into Any	Pin	l <sub>IN</sub>	±10	mA
Maximum Junction Te	nperature	T <sub>J(max)</sub>	+150	°C
Storage Temperature	je Temperature Range		-65 to +150	°C
ESD Capability, Human Body Model (Note 3)		HBM	±2000	V
Charged Device Model (Note 3)		CDM	±1000	V
Latch-up Current (Not	e 4)		±100	mA

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected. 1. Refer to ELECTRICAL CHARACTERISTICS, RECOMMENDED OPERATING RANGES and/or APPLICATION INFORMATION for safe

operating parameters.

Input voltage at any pin may exceed the voltage shown if current at that pin is limited to  $\pm 10$  mA 2.

3. This device series incorporates ESD protection and is tested by the following methods: ESD Human Body Model tested per JEDEC standard JS-001-2017

ESD Charged Device Model tested per JEDEC standard JS-002-2014

4. Latch-up Current tested per JEDEC standard: JESD78E

#### THERMAL CHARACTERISTICS

Parameter	Symbol	Package	Value	Unit
Thermal Resistance, Junction-to-Air (Notes 5, 6)	$\theta_{JA}$	TSOP-5 / SOT23-5	208	°C/W
		Micro8 / MSOP-8	162	

5. Refer to ELECTRICAL CHARACTERISTICS, RECOMMENDED OPERATING RANGES and/or APPLICATION INFORMATION for safe operating parameters
6. Values based on copper area of 645 mm<sup>2</sup> (or 1 in<sup>2</sup>) of 1 oz copper thickness and FR4 PCB substrate

#### **RECOMMENDED OPERATING RANGES**

Parameter	Symbol	Conditions	Min	Max	Unit
Operating Temperature	T <sub>A</sub>	NCS prefix	-40	125	°C
		NCV prefix	-40	150	
Common Mode Input Voltage	V <sub>CM</sub>	Full temperature range	-0.1	40	V
Supply Voltage	V <sub>S</sub>	Full temperature range	2.7	5.5	V

Functional operation above the stresses listed in the Recommended Operating Ranges is not implied. Extended exposure to stresses beyond the Recommended Operating Ranges limits may affect device reliability.

\*During operation at Ta = 150°C the limitation for junction temperature (Tj(max) = 150°C) must be considered.

#### **ELECTRICAL CHARACTERISTICS**

At  $T_A = +25^{\circ}$ C,  $V_{SENSE} = (V_{IN+}) - (V_{IN-})$ ;  $V_S = 5$  V,  $V_{IN+} = 12$  V, unless otherwise noted. **Boldface** limits apply over the specified temperature range,  $T_A = -40^{\circ}$ C to  $125^{\circ}$ C unless otherwise noted, guaranteed by characterization and/or design.

Parameter	Symbol		Conditions			Тур	Max	Unit	
INPUT									
Common Mode Rejection Ratio	CMRR	$V_{IN+} = -0.1 V$	NCS21673	G = 20	-	100	-	dB	
(RTI)*		to 40 V, V <sub>SENSE</sub> =			86	-	-		
		0 mV for G20, G50 and	NCS21674		-	TBD	-		
		G100	G100			TBD	-	-	
		V <sub>SENSE</sub> = 5 mV for G200	NCS2167x	G = 50	-	100	-		
					86	-	-		
				G = 100	-	110	-		
					96	-	-		
			G = 200	-	120	-			
					100	-	_		
Input Offset Voltage (RTI)*	V <sub>OS</sub>	T <sub>A</sub> = 25°C,	NCS21673	G = 20	-	±100	±500	μV	
		(V <sub>IN+</sub> ) = (V <sub>IN</sub> ) = 12 V	$(V_{IN+}) = (V_{IN-})$ = 12 V NCS21674	-	TBD	TBD			
			NCS2167x	G = 50	-	±100	±550		
				G = 100	-	±100	±500		
				G = 200	-	±100	±500		
		$T_A = 25^{\circ}C,$	NCS21673	G = 20	-	±25	±175		
		(V <sub>IN+</sub> ) = (V <sub>IN-</sub> ) = 0 V	NCS21674		-	TBD	TBD		
				NCS2167x	G = 50	-	±25	±175	
				G = 100	-	±25	±175		
				G = 200	-	±25	±210		
Input Offset Voltage Drift vs.	dV <sub>OS</sub> /dT	$T_A = -40^{\circ}C$ to	NCS2	21673	-	±0.1	±0.5	μV/°C	
Temperature (RTI)*		+125°C	NCS2	21674	-	±0.2	±1		
Power Supply Rejection Ratio (RTI)*	PSRR	VS = 2.7 V to 5.5 V, V <sub>SENSE</sub> = 10 mV for	NCS2	21673	-	2	20	μV/V	
		G20, G50 and G100 V <sub>SENSE</sub> = 5 mV for G200	NCS2	21674	-	8	40		
Input Bias Current	I <sub>IB</sub>	V <sub>IN+</sub> = 0 V	V <sub>IN+</sub> = 0 V		-	1	-	μΑ	
		(V <sub>IN+</sub> ) = (V <sub>IN-</sub> ) =	= 12 V		-	100	-		
Input Offset Current	Ι <sub>ΙΟ</sub>	$\label{eq:VIN+} \begin{array}{l} V_{IN+} = 12 \text{ V}, \\ V_{SENSE} = 10 \text{ m}^{\prime} \\ G20, \ G50 \text{ and } C \\ V_{SENSE} = 5 \text{ m} \end{array}$	G100		-	±15	_	μΑ	

**ELECTRICAL CHARACTERISTICS** (continued) At  $T_A = +25^{\circ}$ C,  $V_{SENSE} = (V_{IN+}) - (V_{IN-})$ ;  $V_S = 5$  V,  $V_{IN+} = 12$  V, unless otherwise noted. **Boldface** limits apply over the specified temperature range,  $T_A = -40^{\circ}$ C to  $125^{\circ}$ C unless otherwise noted, guaranteed by characterization and/or design.

Parameter	Symbol	Conditions	Min	Тур	Max	Unit
OUTPUT				-		
Gain	G	G 20	-	20	-	V/V
		G 50	-	50	-	
		G 100	-	100	-	
		G 200	-	200	-	
Gain Error		$T_A = 25^{\circ}C$	-	±0.1	-	%
		$T_A = -40^{\circ}C$ to $+125^{\circ}C$	-	-	±0.4	
Gain Error vs Temperature		$T_A = -40^{\circ}C$ to $+125^{\circ}C$	-	±1.5	±20	ppm/°C
Nonlinearity Error			-	±0.01	-	%
Maximum Capacitive Load	CL	No sustained oscillation	-	1	_	nF
Settling Time to 1%			-	5	_	μs

#### **VOLTAGE OUTPUT**

Output Voltage High, Swing from V <sub>S</sub> Supply Rail	V <sub>S</sub> – V <sub>OH</sub>	$V_S$ = 5.5 V $R_L$ = 10 k $\Omega$ to GND, $T_A$ = 25°C	-	0.02	-	V
		$V_{S} = 5.5 V$ $R_{L} = 10 k to GND,$ $T_{A} = -40^{\circ}C to 125^{\circ}C$	-	-	0.03	
Output Voltage Low, Swing from GND	V <sub>OL</sub> – GND	$V_S = 5.5 V$ R <sub>L</sub> = 10 k to GND, T <sub>A</sub> = 25°C	-	0.0005	-	V
		$ \begin{array}{l} V_S = 5.5 \ V \\ R_L = 10 \ k \ to \ GND, \\ T_A = -40^\circ C \ to \ 125^\circ C \end{array} $	-	-	0.005	

#### FREQUENCY RESPONSE

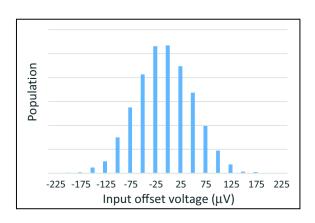
Bandwidth (f <sub>-3dB</sub> )	BW	C <sub>L</sub> = 25 pF	G = 20	-	409	-	kHz
			G = 50	-	270	-	
			G = 100	-	240	-	
			G = 200	-	150	-	
Slew Rate (Note 7)	SR			-	2	-	V/μs
NOISE							
Voltage Noise Density (RTI)*	e <sub>n</sub>	F = 1 kHz, G100		-	25	-	nV/√Hz
POWER SUPPLY							

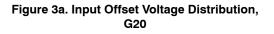
Quiescent Current per	lq	$T_A = 25^{\circ}C$	-	195	260	μΑ	
Channel		$T_A = -40^{\circ}C \text{ to } +125^{\circ}C$	-	-	300		

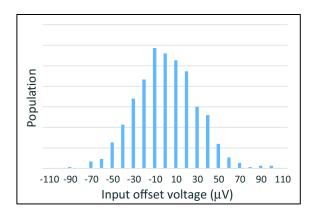
Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions. \*RTI = Referred to input.

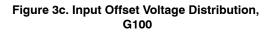
7. Guaranteed by characterization and/or design.

**TYPICAL CHARACTERISTICS** (At  $T_A = +25^{\circ}C$ ,  $V_{SENSE} = (V_{IN+}) - (V_{IN-})$ ,  $V_S = 5.0$  V,  $V_{IN+} = 12$  V, and all gains unless otherwise noted.)









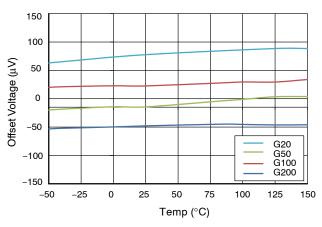


Figure 4. Input Offset vs. Temperature

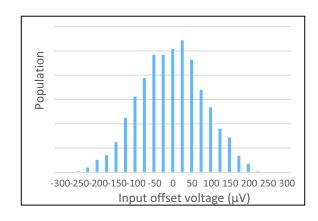


Figure 3b. Input Offset Voltage Distribution, G50

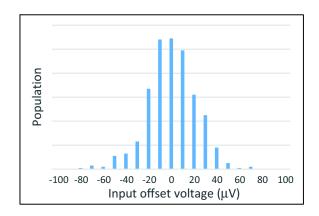
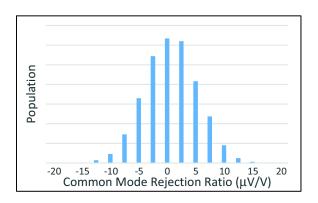


Figure 3d. Input Offset Voltage Distribution, G200





**TYPICAL CHARACTERISTICS** (At  $T_A = +25^{\circ}C$ ,  $V_{SENSE} = (V_{IN+}) - (V_{IN-})$ ,  $V_S = 5.0$  V,  $V_{IN+} = 12$  V, and all gains unless otherwise noted.) (continued)

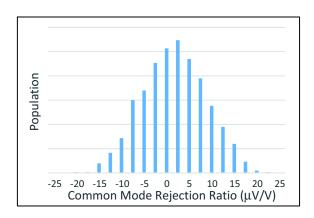


Figure 5b. Common Mode Rejection Ratio Distribution, G50

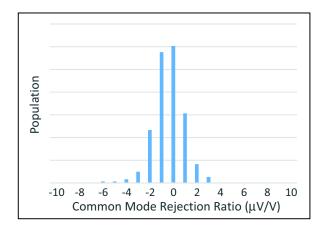


Figure 5d. Common Mode Rejection Ratio Distribution, G200

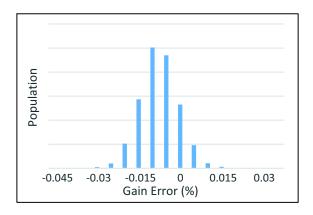


Figure 7a. Gain Error Distribution, G20

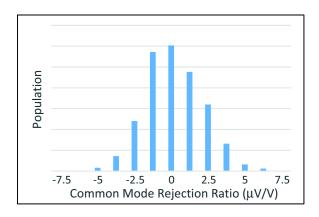


Figure 5c. Common Mode Rejection Ratio Distribution, G100

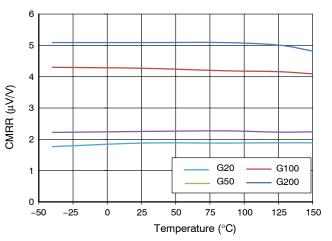


Figure 6. Common Mode Rejection Ratio vs Temperature

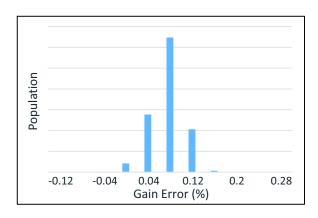


Figure 7b. Gain Error Distribution, G50

**TYPICAL CHARACTERISTICS** (At  $T_A = +25^{\circ}C$ ,  $V_{SENSE} = (V_{IN+}) - (V_{IN-})$ ,  $V_S = 5.0$  V,  $V_{IN+} = 12$  V, and all gains unless otherwise noted.) (continued)

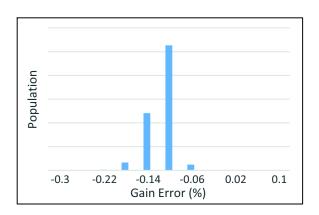


Figure 7c. Gain Error Distribution, G100

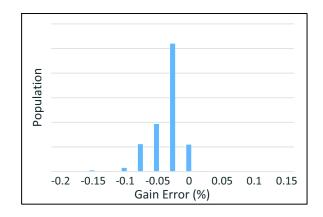
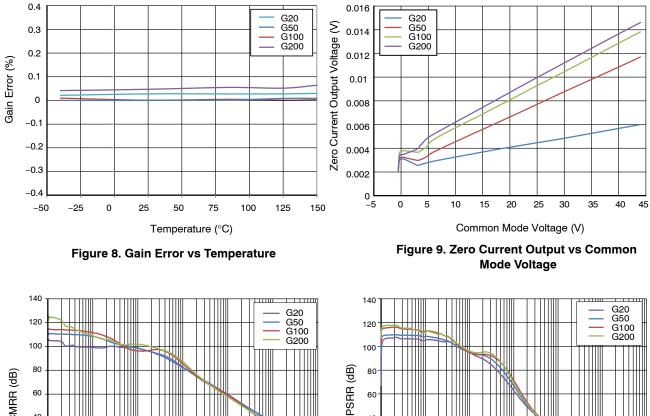


Figure 7d. Gain Error Distribution, G200



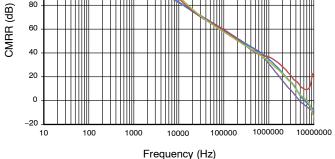
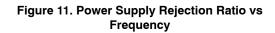


Figure 10. Common Mode Rejection Ratio vs Frequency



10000

Frequency (Hz)

100000

1000000 1000000

60

40

20

0

-20

10

100

1000

**TYPICAL CHARACTERISTICS** (At  $T_A = +25^{\circ}C$ ,  $V_{SENSE} = (V_{IN+}) - (V_{IN-})$ ,  $V_S = 5.0$  V,  $V_{IN+} = 12$  V, and all gains unless otherwise noted.) (continued)

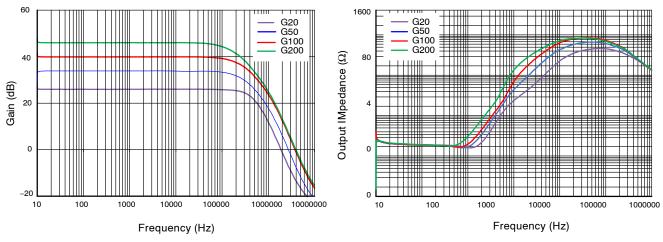




Figure 13. Output Impedance vs Frequency

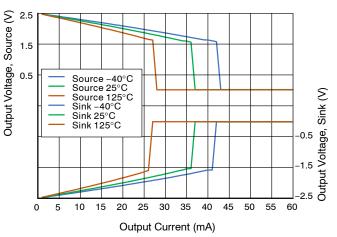


Figure 14. Output Voltage Swing vs Current

120

100

80

60

40

20

0

0

Input Bias Current (µA)

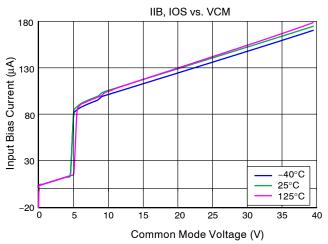
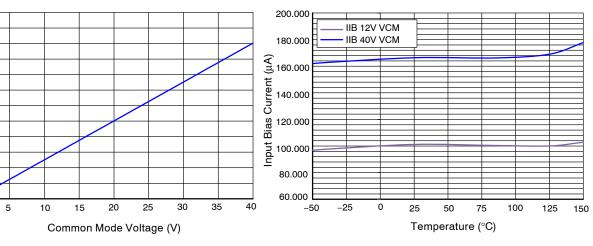


Figure 15. Input Bias Current vs Common Mode Voltage



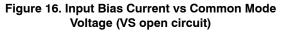
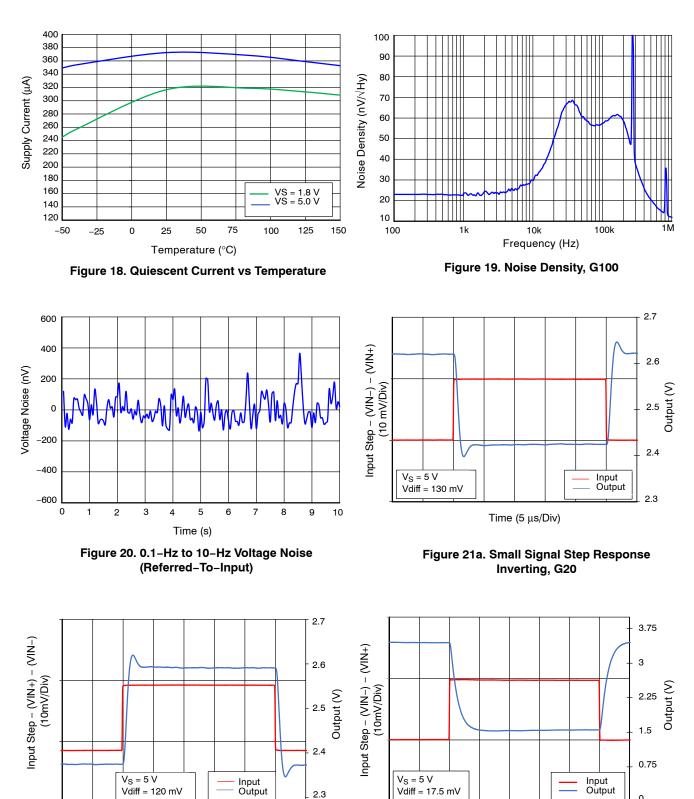


Figure 17. Input Bias Current vs Temperature

**TYPICAL CHARACTERISTICS** (At  $T_A = +25^{\circ}C$ ,  $V_{SENSE} = (V_{IN+}) - (V_{IN-})$ ,  $V_S = 5.0$  V,  $V_{IN+} = 12$  V, and all gains unless otherwise noted.) (continued)



Time (5 µs/Div)

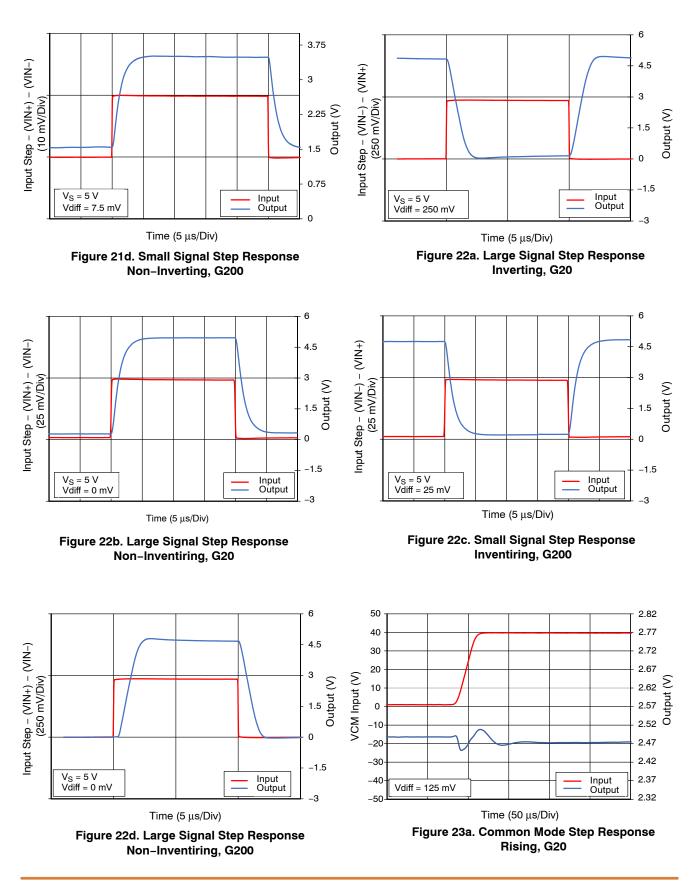




0

Inverting, G200

**TYPICAL CHARACTERISTICS** (At  $T_A = +25^{\circ}C$ ,  $V_{SENSE} = (V_{IN+}) - (V_{IN-})$ ,  $V_S = 5.0 \text{ V}$ ,  $V_{IN+} = 12 \text{ V}$ , and all gains unless otherwise noted.) (continued)



**TYPICAL CHARACTERISTICS** (At  $T_A = +25^{\circ}C$ ,  $V_{SENSE} = (V_{IN+}) - (V_{IN-})$ ,  $V_S = 5.0$  V,  $V_{IN+} = 12$  V, and all gains unless otherwise noted.) (continued)

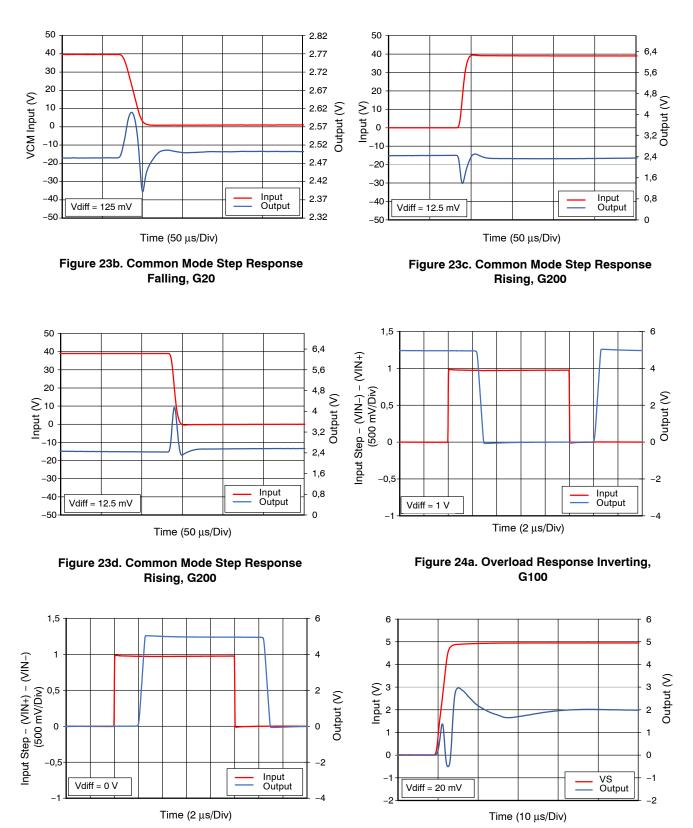


Figure 24b. Overload Response Non-Inverting, G100

Figure 25a. Startup Response, G100

**TYPICAL CHARACTERISTICS** (At  $T_A = +25^{\circ}C$ ,  $V_{SENSE} = (V_{IN+}) - (V_{IN-})$ ,  $V_S = 5.0$  V,  $V_{IN}$ + = 12 V, and all gains unless otherwise noted.) (continued)

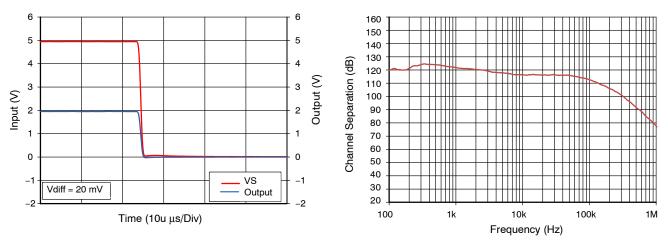


Figure 25b. Shutdown Response, G100

Figure 26. Channel Separation, G200

#### **APPLICATION INFORMATION**

#### **Current Sensing Techniques**

NCS(V)21673 and NCS(V)21674 are current sense amplifiers featuring a wide common mode voltage range that spans from -0.1 V to -40 V independent of the supply voltage. These amplifiers can be configured for low-side and high-side current sensing.

#### **Unidirectional Operation**

In unidirectional current sensing, the measured load current always flows in the same direction. Common applications for unidirectional operation include power supplies and load current monitoring. In this configuration, the IN+ pin should be connected to the high side of the sense resistor, while the IN- pin should be connected to the low side of the sense resistor.

#### Input Filtering

As shunt resistors decrease in value, shunt inductance can significantly affect frequency response. At values below 1 m, the shunt inductance causes a zero in the transfer function that often results in corner frequencies in the low 100's of kHz. This inductance increases the amplitude of high frequency spike transient events on the current sensing line that can overload the front end of any shunt current sensing IC. This problem must be solved by external filtering at the input of the amplifier. Note that all current sensing IC's are vulnerable to this problem, regardless of manufacturer claims. Filtering is required at the input of the device to resolve this problem, even if the spike frequencies are above the rated -3 dB bandwidth of the device.

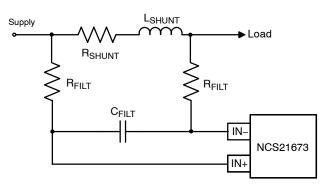


Figure 27.

Ideally, select the capacitor to exactly match the time constant of the shunt resistor and its inductance; alternatively, select the capacitor to provide a pole below that point. Make the input filter time constant equal to or larger than the shunt and its inductance time constant:

$$Freq_{Zero} = 2\pi R_{Shunt} L_{Shunt}$$
 (eq. 1)

$$Freq_{Pole} = \frac{1}{2\pi (2R_{Filt})C_{Filt}}$$
 (eq. 2)

While this time constant can be the product of any RFILT and  $C_{FILT}$  values, the designer needs to take into account that

the RFILT resistors are connected in series with the internal feedback resistors R3 and R4, hence changing the amplifier's overall gain. Also, the Opamp's input (IIB) currents create a voltage drop across the filtering resistors, which is added to the differential voltage presented to the Opamp's inputs. This voltage is gained by the amplifier adding to the overall error. A good practice is to keep the filtering resistors in the range of a few ohms then size the filtering capacitor accordingly.

The zero-drift architecture contains a 250 KHz sampling circuit that can induce aliasing effects on the current signal. It is recommended to add filtering to the input stage that limits the signal bandwidth to <100 KHz for current signals with high ac spectral content.

#### Selecting the Shunt Resistor

The desired accuracy of the current measurement determines the precision, shunt size, and the resistor value. The larger the resistor value, the more accurate the measurement possible, but a large resistor value also results in greater current loss.

For the most accurate measurements, use four-terminal current sense resistors. They provide two terminals for the current path in the application circuit, and a second pair for the voltage detection path of the sense amplifier. This technique is also known as *Kelvin Sensing*. This ensures that the voltage measured by the sense amplifier is the actual voltage across the resistor and does not include the small resistance of a combined connection. When using non-Kelvin shunts, follow manufacturer recommendations on how to lay out the sensing traces closely.

#### Gain Options

The gain is set by integrated, precision, ratio-matched resistors. These current sense amplifiers are available in gain options of 20 V/V, 50 V/V, 100 V/V, and 200 V/V. Adding external resistors to adjust the gain can contribute to the overall system error and is not recommended for multiple reasons. First, the series resistor's mismatch increases the overall gain error and temperature coefficient and lowers the CMRR. Second, the IIB flowing through the external resistors change the differential voltage seen by the opamp's input. Finally, while the internal resistors are well matched in terms of ratio, they have a high tolerance in their absolute value so the resulting gain value may not match the expectations.

#### Shutdown

While the NCS21673/4 series do not include a shutdown feature, a simple MOSFET, power switch, or logic gate can be used to switch off power and eliminate quiescent current. Note that the input pins connected to the shunt resistor will always have a current flow via the input and feedback resistors (total resistance of each leg is always ~ 400 k $\Omega$ ). If unpowered, common mode voltage will feedthrough the

Also note that when powered, the shunt input pins will

exhibit the specified and well-matched bias current. The shunt input pins support the rated common mode voltage

when the power is not applied

VIN– terminal to the output which forms a divider with the 400 k $\Omega$ . Vout under unpowered conditions will be:

$$Vout = \frac{VIN_(Rload)}{400K + (Rload)}$$
(eq. 3)

Load resistance to ground should be added to keep Vout within required system limits under this condition.

#### **ORDERING INFORMATION**

Device	Channels	Package	Gain	OPN	Marking	Shipping <sup>†</sup>		
INDUSTRIAL AND CONSUMER								
NCS21673	Single	TSOP-5	20	NCS21673SN2G020T1G**	AE2	Tape and Reel		
			50	NCS21673SN2G050T1G**	AE3	3000 / Reel		
			100	NCS21673SN2G100T1G**	AE4			

				100	NCS21673SN2G100T1G**	AE4	
				200	NCS21673SN2G200T1G**	AE5	
ĺ	NCS21674	Dual	Micro8	20	NCS21674DMG020R2G**	G020	Tape and Reel 4000 / Reel
				50	NCS21674DMG050R2G	G050	4000 / Reel
				100	NCS21674DMG100R2G	G100	
				200	NCS21674DMG200R2G	G200	

#### AUTOMOTIVE QUALIFIED

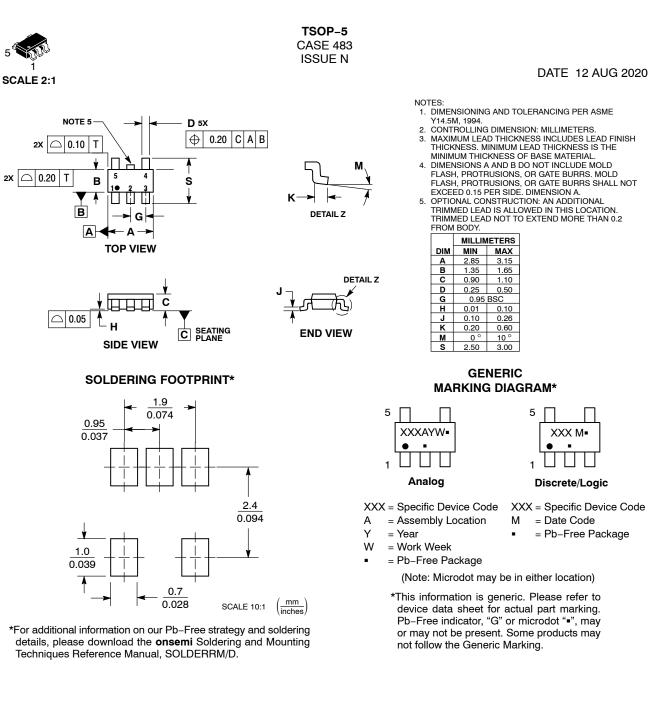
NCV21673*	Single	TSOP-5	20	NCV21673SN2G020T1G**	AE2	Tape and Reel 3000 / Reel
			50	NCV21673SN2G050T1G**	AE3	
			100	NCV21673SN2G100T1G**	AE4	
			200	NCV21673SN2G200T1G**	AE5	
NCV21674*	Dual	Micro8	20	NCV21674DMG020R2G**	G020	Tape and Reel
			50	NCV21674DMG050R2G	G050	4000 / Reel
		100	NCV21674DMG100R2G	G100		
			200	NCV21674DMG200R2G	G200	

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

\*NCV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q100 Qualified and PPAP Capable

\*\*In Development / Consult Sales

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